

HD74ALVC2G02

Dual 2-input NOR Gates

REJ03D0160-0400Z (Previous ADE-205-611C (Z)) Rev.4.00 Dec.16.2003

Description

The HD74ALVC2G02 has two-input NOR gate in an 8 pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Supply voltage range: 1.2 to 3.6 V
 Operating temperature range: -40 to +85°C
- All inputs V_{IH} (Max.) = 3.6 V (@ V_{CC} = 0 V to 3.6 V)

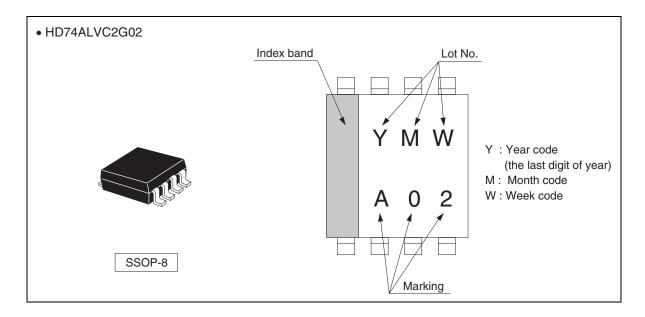
All outputs
$$V_0$$
 (Max.) = 3.6 V (@V_{CC} = 0 V)

$$\begin{array}{ll} \bullet & \text{Output current} & \pm 2 \text{ mA } (@V_{CC} = 1.2 \text{ V}) \\ & \pm 4 \text{ mA } (@V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}) \\ & \pm 6 \text{ mA } (@V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}) \\ & \pm 18 \text{ mA } (@V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}) \\ & \pm 24 \text{ mA } (@V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}) \end{array}$$

• Ordering Information

| Part Name | Package Type | Package Code | Package Abbreviation | Taping Abbreviation (Quantity) |
|-----------------|--------------|--------------|-------------------------|--------------------------------|
| HD74ALVC2G02USE | SSOP-8 pin | TTP-8DBV | US | E (3,000 pcs/reel) |

Outline and Article Indication



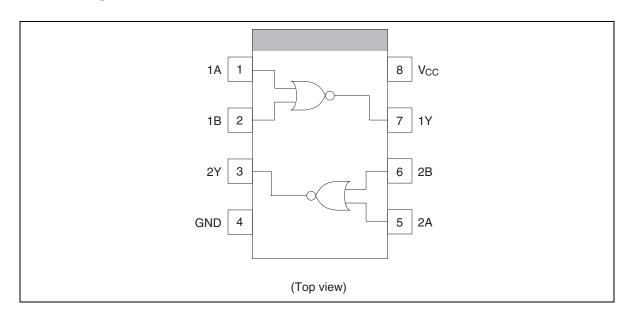
Function Table

Inputs

| A | В | Output Y |
|---|---|----------|
| L | L | Н |
| L | Н | L |
| Н | L | L |
| Н | Н | L |

H: High level L: Low level

Pin Arrangement



Absolute Maximum Ratings

| Item | Symbol | Ratings | Unit | Conditions |
|--|-------------------------------------|------------------------------|------|-----------------------------|
| Supply voltage range | V _{CC} | -0.5 to 4.6 | V | |
| Input voltage range *1 | VI | -0.5 to 4.6 | V | |
| Output voltage range *1, 2 | Vo | -0.5 to V _{CC} +0.5 | V | Output : H or L |
| | | -0.5 to 4.6 | _ | V _{CC} : OFF |
| Input clamp current | I _{IK} | -50 | mA | V _I < 0 |
| Output clamp current | I _{OK} | ±50 | mA | $V_O < 0$ or $V_O > V_{CC}$ |
| Continuous output current | lo | ±50 | mA | $V_O = 0$ to V_{CC} |
| Continuous current through V _{CC} or GND | I _{CC} or I _{GND} | ±100 | mA | |
| Maximum power dissipation at Ta = 25°C (in still air) *3 | P _T | 200 | mW | |
| Storage temperature | Tstg | -65 to 150 | °C | |

Notes:

- The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 4.6 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

HD74ALVC2G02

Recommended Operating Conditions

| Item | Symbol | Min | Max | Unit | Conditions |
|------------------------------------|-----------------|-----|-----------------|--------|----------------------------------|
| Supply voltage range | V _{CC} | 1.2 | 3.6 | V | |
| Input voltage range | Vı | 0 | 3.6 | V | |
| Output voltage range | Vo | 0 | V _{CC} | V | |
| Output current | I _{OH} | _ | -2 | mA | V _{CC} = 1.2 V |
| | | _ | -4 | | V _{CC} = 1.4 V |
| | | _ | -6 | | V _{CC} = 1.65 V |
| | | _ | -18 | | $V_{CC} = 2.3 \text{ V}$ |
| | | _ | -24 | | V _{CC} = 3.0 V |
| | I _{OL} | _ | 2 | | V _{CC} = 1.2 V |
| | | _ | 4 | | V _{CC} = 1.4 V |
| | | _ | 6 | | V _{CC} = 1.65 V |
| | | _ | 18 | | $V_{CC} = 2.3 \text{ V}$ |
| | | _ | 24 | | $V_{CC} = 3.0 \text{ V}$ |
| Input transition rise or fall rate | Δt / Δν | 0 | 20 | ns / V | V _{CC} = 1.2 to 2.7 V |
| | | 0 | 10 | | $V_{CC} = 3.3 \pm 0.3 \text{ V}$ |
| Operating free-air temperature | Та | -40 | 85 | °C | |

Note: Unused or floating inputs must be held high or low.

Electrical Characteristics

 $(Ta = -40 \text{ to } 85^{\circ}C)$

| Item | Symbol | $V_{CC}(V)^*$ | Min | Тур | Max | Unit | Test conditions |
|--------------------------|------------------|---------------|-----------------------|-----|-----------------------|------|--|
| Input voltage | V _{IH} | 1.2 | V _{CC} ×0.75 | _ | _ | V | |
| | | 1.4 to 1.6 | V _{CC} ×0.7 | _ | _ | _ | |
| | | 1.65 to 1.95 | V _{CC} ×0.7 | _ | _ | _ | |
| | | 2.3 to 2.7 | 1.7 | _ | _ | _ | |
| | | 3.0 to 3.6 | 2.0 | _ | _ | _ | |
| | V _{IL} | 1.2 | _ | _ | V _{CC} ×0.25 | _ | |
| | | 1.4 to 1.6 | _ | _ | V _{CC} ×0.3 | _ | |
| | | 1.65 to 1.95 | _ | _ | V _{CC} ×0.3 | _ | |
| | | 2.3 to 2.7 | _ | _ | 0.7 | _ | |
| | | 3.0 to 3.6 | _ | _ | 0.8 | = | |
| Output voltage | V _{OH} | Min to Max | V _{CC} -0.2 | _ | _ | V | $I_{OH} = -100 \mu A$ |
| | | 1.2 | 0.9 | _ | _ | _ | $I_{OH} = -2 \text{ mA}$ |
| | | 1.4 | 1.1 | _ | _ | _ | $I_{OH} = -4 \text{ mA}$ |
| | | 1.65 | 1.2 | _ | _ | _ | $I_{OH} = -6 \text{ mA}$ |
| | | 2.3 | 1.7 | _ | _ | = | $I_{OH} = -18 \text{ mA}$ |
| | | 3.0 | 2.2 | _ | _ | _ | $I_{OH} = -24 \text{ mA}$ |
| | V _{OL} | Min to Max | _ | _ | 0.2 | _ | $I_{OL} = 100 \mu A$ |
| | | 1.2 | _ | _ | 0.3 | _ | I _{OL} = 2 mA |
| | | 1.4 | _ | _ | 0.3 | _ | I _{OL} = 4 mA |
| | | 1.65 | _ | _ | 0.3 | _ | I _{OL} = 6 mA |
| | | 2.3 | _ | _ | 0.55 | = | I _{OL} = 18 mA |
| | | 3.0 | _ | _ | 0.55 | _ | I _{OL} = 24 mA |
| Input current | I _{IN} | 3.6 | _ | _ | ±5 | μΑ | V _{IN} = 3.6 V or GND |
| Quiescent supply current | I _{CC} | 3.6 | _ | _ | 10 | μΑ | $V_{IN} = V_{CC}$ or GND, $I_O = 0$ |
| Output leakage current | I _{OFF} | 0 | _ | _ | 5 | μΑ | V_{IN} or $V_O =$ 0 to 3.6 V |
| Input capacitance | C _{IN} | 3.3 | _ | 4.5 | _ | рF | V _{IN} = V _{CC} or GND |
| | | | | | | | |

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

 $(Ta = -40 \text{ to } 85^{\circ}C)$

 $V_{CC} = 1.2 \text{ V}$

| Item | Symbol | Min | Тур | Max | Unit | Test conditions | FROM (Input) | TO (Output) |
|------------------------|--------------------------------------|-----|-----|-----|------|-----------------|-----------------|----------------|
| Propagation delay time | t _{PLH} t _{PHL} | _ | 7.5 | _ | ns | $C_L = 15 pF$ | A or B | Υ |

 $V_{CC} = 1.5 \pm 0.1 \text{ V}$

| Item | Symbol | Min | Тур | Max | Unit | Test conditions | FROM (Input) | TO (Output) |
|------------------------|--------------------------------------|-----|-----|-----|------|------------------------|-----------------|----------------|
| Propagation delay time | t _{PLH} t _{PHL} | 2.0 | _ | 7.0 | ns | C _L = 15 pF | A or B | Υ |

 $V_{CC} = 1.8 \pm 0.15 \text{ V}$

| Item | Symbol | Min | Тур | Max | Unit | Test conditions | FROM (Input) | TO (Output) |
|------------------------|--------------------------------------|-----|-----|-----|------|-----------------|-----------------|----------------|
| Propagation delay time | t _{PLH} t _{PHL} | 1.5 | _ | 5.0 | ns | $C_L = 30 pF$ | A or B | Υ |

 $V_{CC} = 2.5 \pm 0.2 \text{ V}$

| Item | Symbol | Min | Тур | Max | Unit | conditions | (Input) | (Output) |
|------------------------|--------------------------------------|-----|-----|-----|------|---------------|---------|----------|
| Propagation delay time | t _{PLH} t _{PHL} | 1.0 | _ | 3.7 | ns | $C_L = 30 pF$ | A or B | Υ |

 $V_{CC} = 3.3 \pm 0.3 \text{ V}$

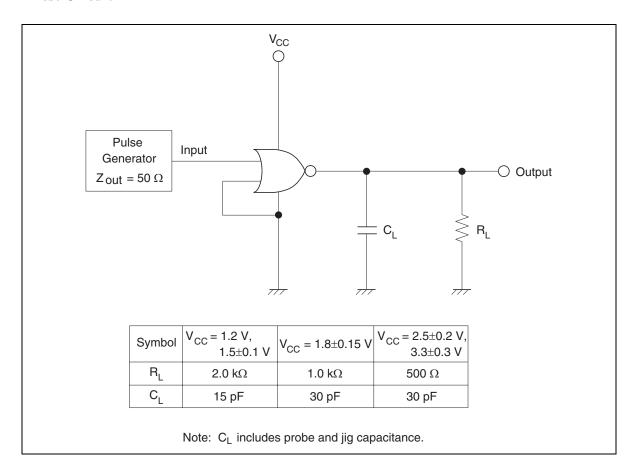
| Item | Symbol | Min | Тур | Max | Unit | Test conditions | FROM (Input) | TO (Output) |
|------------------------|--------------------------------------|-----|-----|-----|------|-----------------|-----------------|----------------|
| Propagation delay time | t _{PLH} t _{PHL} | 1.0 | _ | 2.8 | ns | $C_L = 30 pF$ | A or B | Υ |

Operating Characteristics

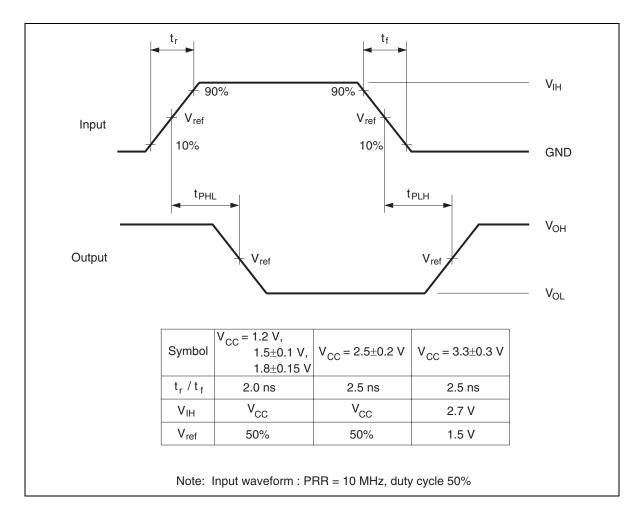
 $(Ta = 25^{\circ}C)$

| Item | Symbol | V _{CC} (V) | Min | Тур | Max | Unit | Test conditions |
|-------------------|-----------------|---------------------|-----|------|-----|------|-----------------|
| Power dissipation | C _{PD} | 1.5 | _ | 10.5 | _ | pF | f = 10 MHz |
| capacitance | | 1.8 | _ | 10.5 | _ | _ | |
| | | 2.5 | _ | 10.5 | _ | _ | |
| | | 3.3 | _ | 11.5 | _ | _ | |

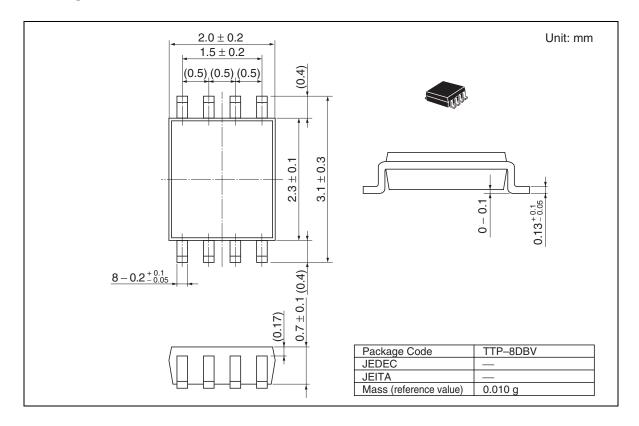
Test Circuit



Waveforms



Package Dimensions



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